### PESD5V0F1BL

# Femtofarad bidirectional ESD protection diode Rev. 3 — 24 October 2011

Product data sheet

### **Product profile**

### 1.1 General description

Femtofarad bidirectional ElectroStatic Discharge (ESD) protection diode in a leadless ultra small SOD882 Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients. The combination of extremely low capacitance, high ESD maximum rating and ultra small package makes the device ideal for high-speed data line protection and antenna protection applications.

#### 1.2 Features and benefits

- Bidirectional ESD protection of one line ESD protection up to 10 kV
- Femtofarad capacitance: C<sub>d</sub> = 400 fF
- Low ESD clamping voltage: 30 V at 30 ns and  $\pm$  8 kV
- Very low leakage current: I<sub>RM</sub> < 1 nA</p>
- IEC 61000-4-2; level 4 (ESD)
- AEC-Q101 qualified

### 1.3 Applications

- 10/100/1000 Mbit/s Ethernet
- FireWire
- High-speed data lines
- Subscriber Identity Module (SIM) card protection
- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals
- Audio and video equipment
- Antenna protection

#### 1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Per device	e					
$V_{RWM}$	reverse standoff voltage		-	-	5.5	V
$C_d$	diode capacitance	$f = 1 MHz; V_R = 0 V$	-	0.4	0.55	pF



### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	1 2	1 2 sym045
		Transparent top view	

### 3. Ordering information

Table 3. Ordering information

Type number Package			
	Name	Description	Version
PESD5V0F1BL	-	leadless ultra small plastic package; 2 terminals; body 1.0 $\times$ 0.6 $\times$ 0.5 mm	SOD882

### 4. Marking

Table 4. Marking codes

Type number	Marking code
· <b>/</b>   · · · · · · · · · · · · · · · · · ·	
PESD5V0F1BL	ZZ

### 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per device					
I <sub>PP</sub>	peak pulse current	$t_p = 8/20 \ \mu s$	<u>[1]</u> -	2.5	Α
T <sub>j</sub>	junction temperature		-	125	°C
T <sub>amb</sub>	ambient temperature		-40	+125	°C
T <sub>stg</sub>	storage temperature		<b>–55</b>	+125	°C

<sup>[1]</sup> Non-repetitive current pulse 8/20  $\mu s$  exponential decay waveform according to IEC 61000-4-5.

Table 6. ESD maximum ratings

 $T_{amb} = 25$  °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit
Per devic	ee				
V <sub>ESD</sub>	electrostatic discharge voltage	IEC 61000-4-2 (contact discharge)	[1] -	10	kV
		MIL-STD-883 (human body model)	-	10	kV

<sup>[1]</sup> Device stressed with ten non-repetitive ESD pulses.

Table 7. ESD standards compliance

Standard	Conditions
Per device	
IEC 61000-4-2; level 4 (ESD)	> 8 kV (contact)
MIL-STD-883; class 3 (human body model)	> 4 kV

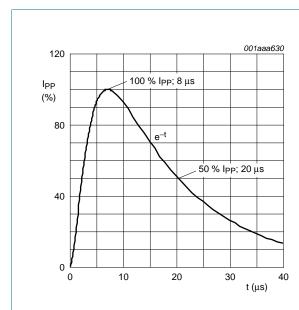


Fig 1. 8/20 µs pulse waveform according to IEC 61000-4-5

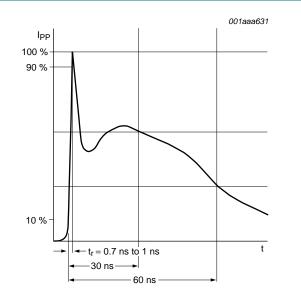


Fig 2. ESD pulse waveform according to IEC 61000-4-2

### 6. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

$\begin{array}{cccccccccccccccccccccccccccccccccccc$	5.5	V nA
$\begin{array}{cccccccccccccccccccccccccccccccccccc$	100	nA
$V_{BR}$ breakdown voltage $I_R = 1 \text{ mA}$ 6 8 $C_d$ diode capacitance $f = 1 \text{ MHz}$ ; $V_R = 0 \text{ V}$ - 0.4		
$C_d$ diode capacitance $f = 1 \text{ MHz}; V_R = 0 \text{ V}$ - 0.4		
	10	V
	0.55	pF
V <sub>CL</sub> clamping voltage [1]		
I <sub>PP</sub> = 1 A	11	V
I <sub>PP</sub> = 2.5 A	15	V
$r_{dif}$ differential resistance $I_R = 20 \text{ mA}$	30	Ω

[1] Non-repetitive current pulse 8/20  $\mu s$  exponential decay waveform according to IEC 61000-4-5.

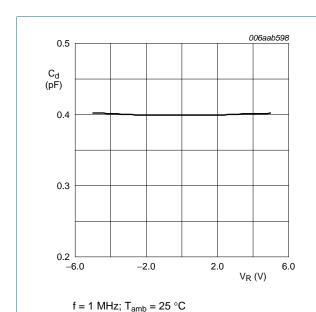


Fig 3. Diode capacitance as a function of reverse voltage; typical values

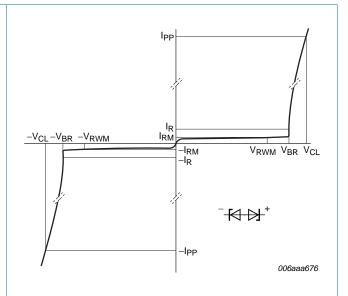
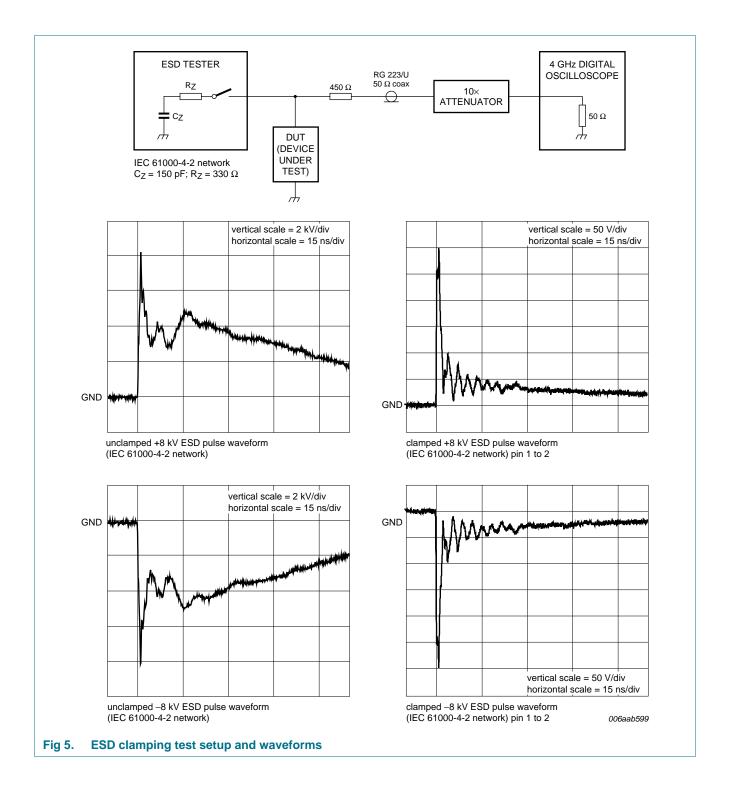
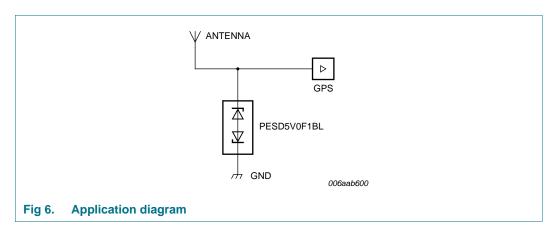


Fig 4. V-I characteristics for a bidirectional ESD protection diode



### 7. Application information

PESD5V0F1BL is designed for the protection of one bidirectional data or signal line from the damage caused by ESD and surge pulses. The device may be used on lines where the signal polarities are both, positive and negative with respect to ground.



#### Circuit board layout and protection device placement

Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

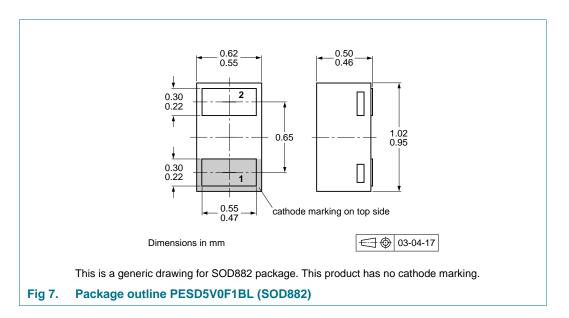
- 1. Place the device as close to the input terminal or connector as possible.
- 2. The path length between the device and the protected line should be minimized.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Ground planes should be used whenever possible. For multilayer PCBs, use ground vias.

#### 8. Test information

#### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

### 9. Package outline



### 10. Packing information

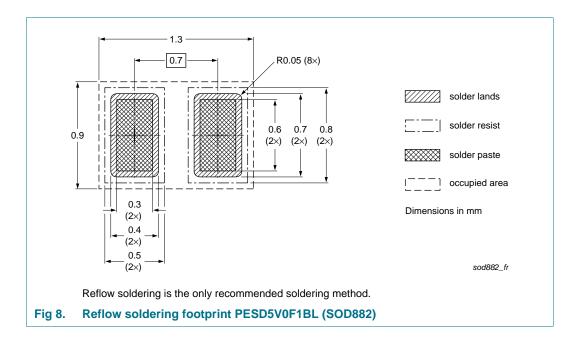
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
PESD5V0F1BL	SOD882	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see  $\underline{\text{Section 14}}$ .

### 11. Soldering





### 12. Revision history

#### Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PESD5V0F1BL v.3	20111024	Product data sheet	-	PESD5V0F1BL v.2
Modifications:	• Figure 7 "Packa	age outline PESD5V0F1BL	. (SOD882)": updated	
	<ul> <li>Section 13 "Leg</li> </ul>	gal information": updated.		
PESD5V0F1BL v.2	20110323	Product data sheet	-	PESD5V0F1BL v.1
PESD5V0F1BL v.1	20091001	Product data sheet	-	-

### 13. Legal information

#### 13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### Femtofarad bidirectional ESD protection diode

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## PESD5V0F1BL

### Femtofarad bidirectional ESD protection diode

### 15. Contents

1	Product profile
1.1	General description 1
1.2	Features and benefits 1
1.3	Applications
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 2
6	Characteristics 4
7	Application information 6
8	Test information 6
8.1	Quality information 6
9	Package outline
10	Packing information 7
11	Soldering 8
12	Revision history 9
13	Legal information
13.1	Data sheet status
13.2	Definitions
13.3	Disclaimers
13.4	Trademarks11
14	Contact information 11
15	Contents 12

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